



# YJL2304A

## N-Channel Enhancement Mode Field Effect Transistor

### Product Summary

$I_{DS}$	30V
$I_D$	3.6A
$r_{DS(ON)}$ (at $V_{GS}=10V$ )	33mohm
$r_{DS(ON)}$ (at $V_{GS}=4.5V$ )	48mohm
$V_{DS}$ Tested	

### General Description

Trench Power MV MOSFET technology  
High Power and current handing capability  
Moisture Sensitivity Level 1  
Epoxy Meets UL 94 V-0 Flammability Rating  
Halogen Free

### Applications

PWM application  
2 2

### Absolute Maximum Ratings ( $T_A=25$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
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## Electrical Characteristics (T<sub>J</sub>=25 unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250	30			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	
Gate-Body Leakage Current	I <sub>GSS1</sub>	V <sub>GS</sub> = 20V, V <sub>DS</sub> =0V			100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =250	1.0	1.5	2.2	V
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3.6A		26	33	m
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A		39	48	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =3.6A, V <sub>GS</sub> =0V			1.2	V
<b>Dynamic Parameters</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ		314		pF
Output Capacitance	C <sub>oss</sub>			59		
Reverse Transfer Capacitance	C <sub>rss</sub>			48		
<b>Switching Parameters</b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =15V, I <sub>D</sub> =3.6A		6.08		nC
Gate-Source Charge	Q <sub>gs</sub>			1.26		
Gate-Drain Charge	Q <sub>gd</sub>			1.32		
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =3.6A, di/dt=100A/us		1.66		ns
Reverse Recovery Time	t <sub>rr</sub>			17.33		
Turn-on Delay Time	t <sub>D(on)</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =15V, R <sub>L</sub> =4.1 R <sub>GEN</sub> =3		3.8		ns
Turn-on Rise Time	t <sub>r</sub>			23.2		
Turn-off Delay Time	t <sub>D(off)</sub>			7		
Turn-off fall Time	t <sub>f</sub>			18.6		

A. Pulse Test: Pulse Width 300us, Duty cycle 2%.

B. R<sub>JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>JC</sub> is guaranteed by design, while R<sub>JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.



### Typical Performance Characteristics

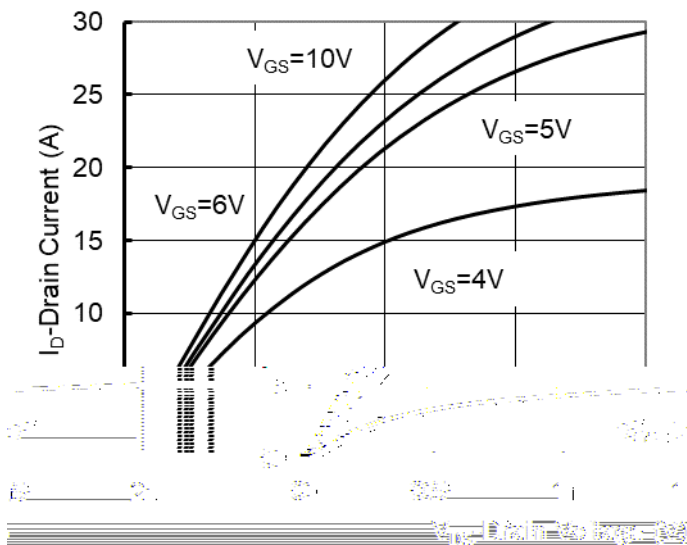


Figure1. Output Characteristics

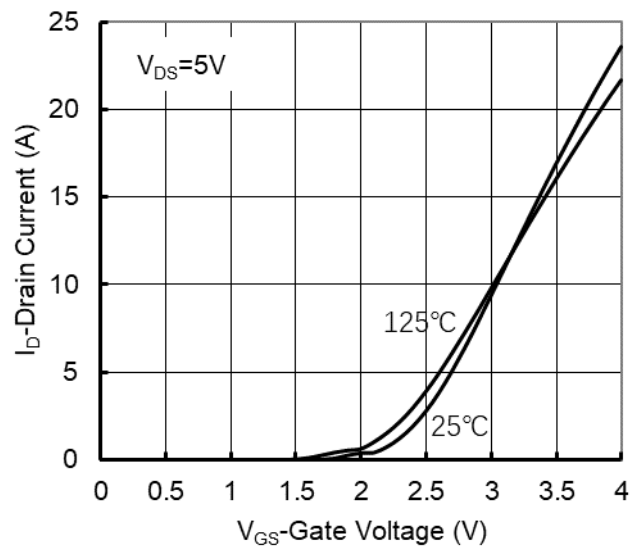


Figure2. Transfer Characteristics

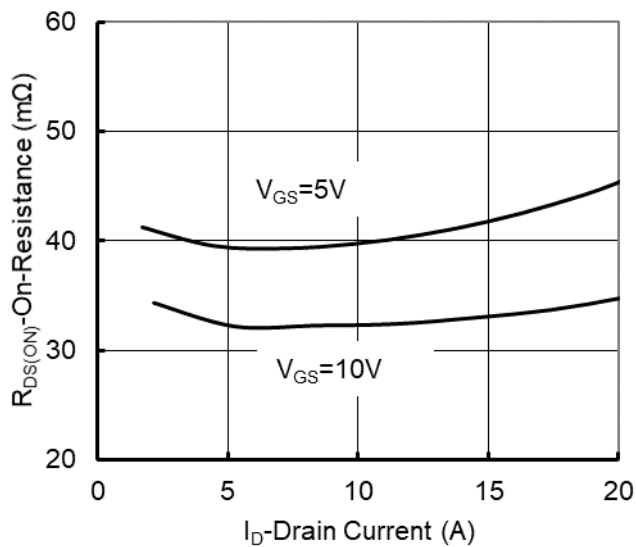


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

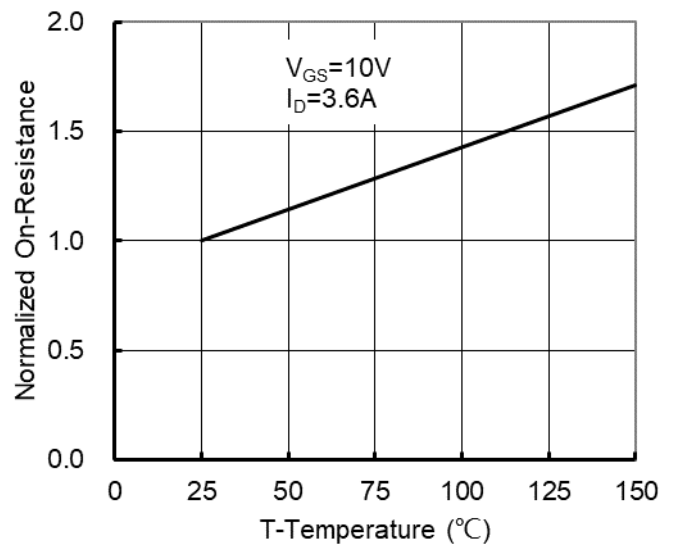


Figure 4: On-Resistance vs. Junction Temperature

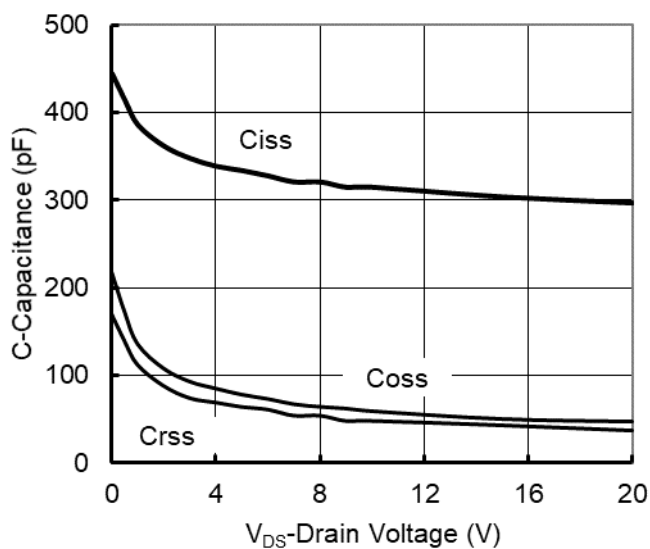


Figure5. Capacitance Characteristics

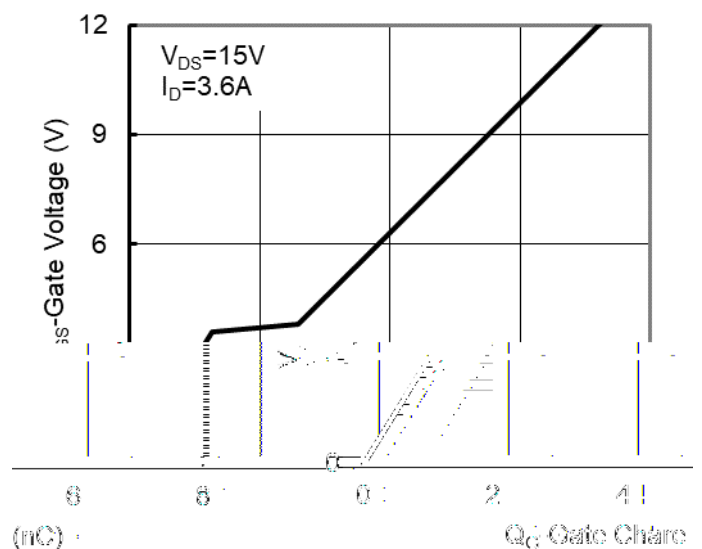


Figure6. Gate Charge



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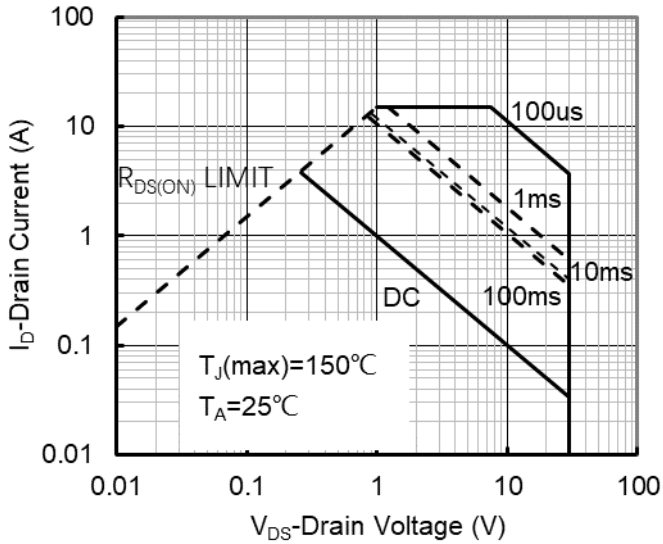


Figure7. Safe Operation Area

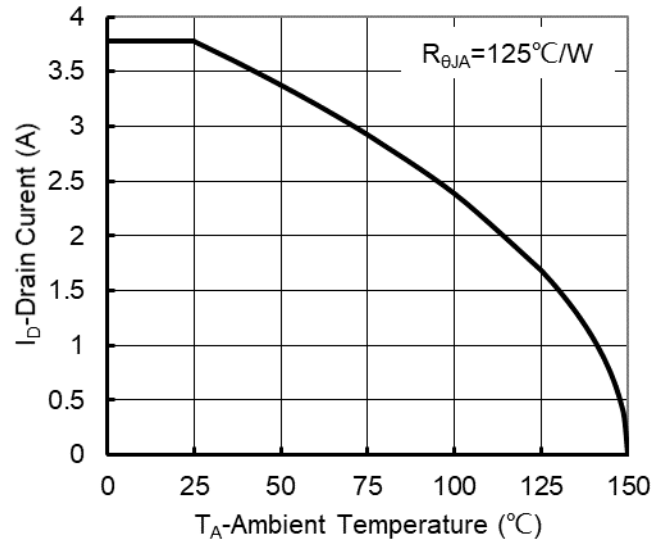


Figure8. Maximum Continuous Drain Current vs Ambient Temperature

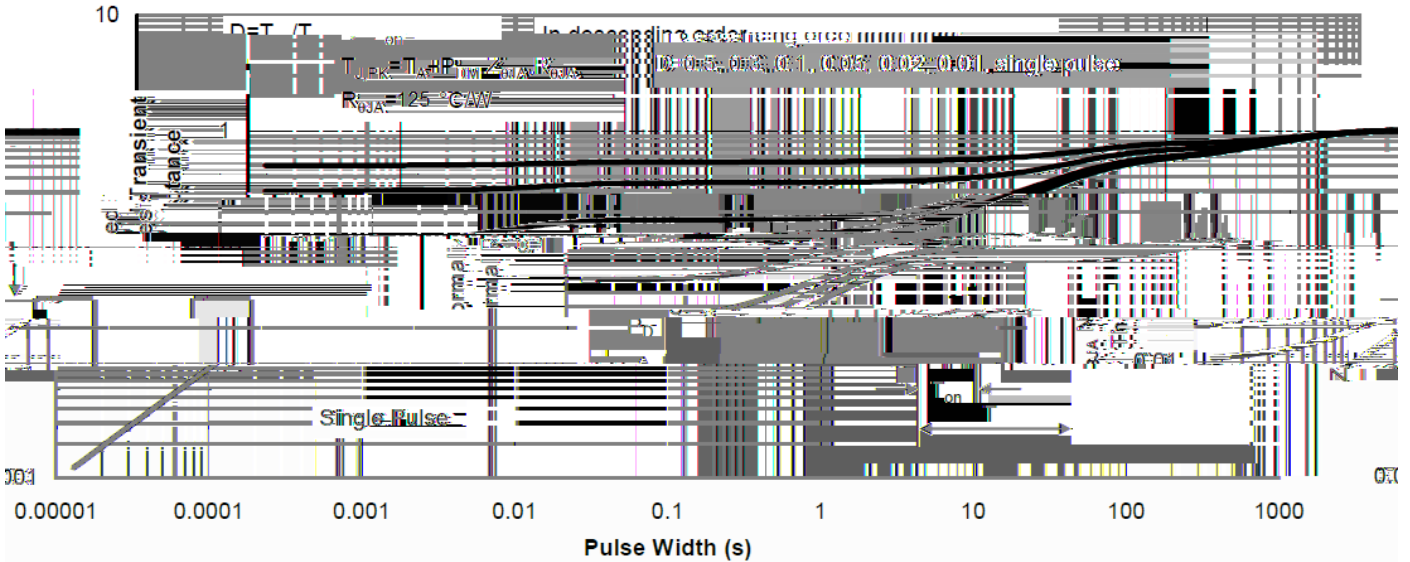
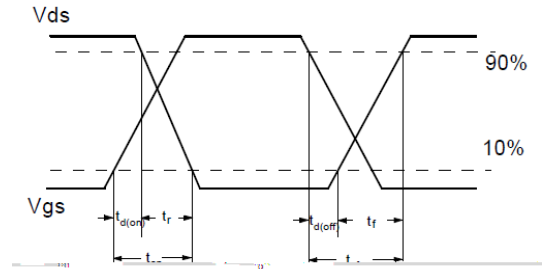
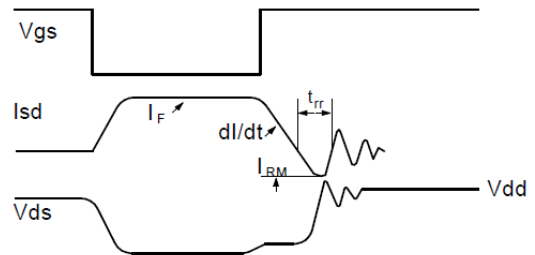
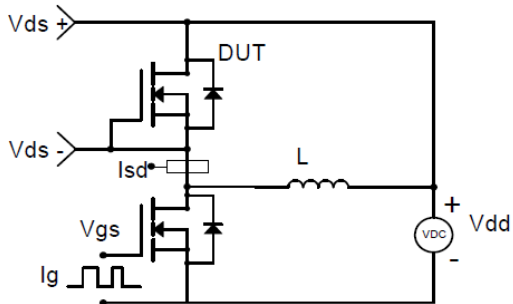


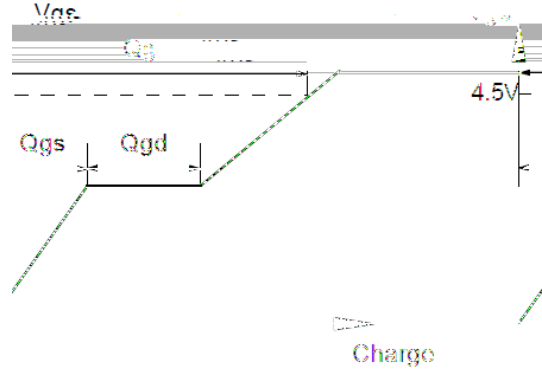
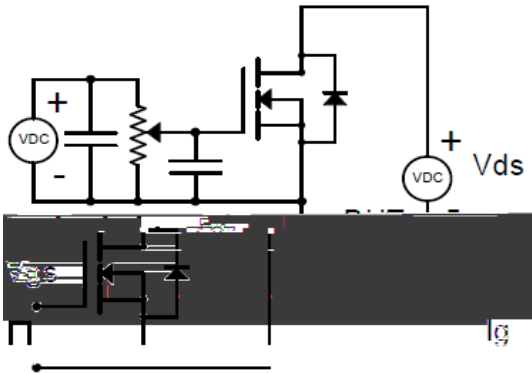
Figure9. Normalized Maximum Transient Thermal Impedance



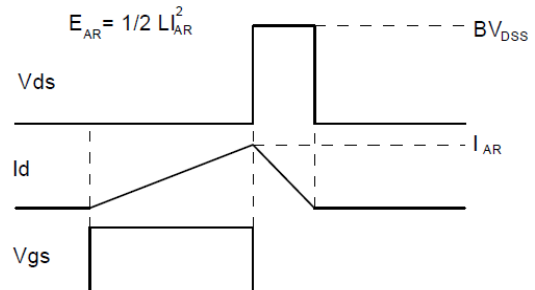
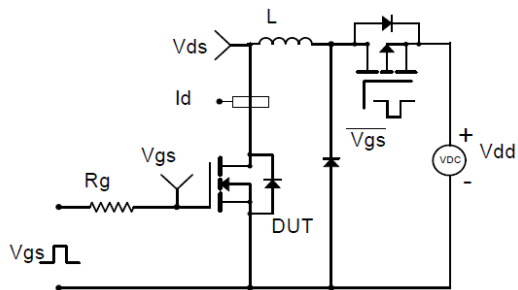
**Resistive Switching Test Circuit & Waveforms**



**Diode Recovery Test Circuit & Waveforms**



**Gate Charge Test Circuit & Waveform**

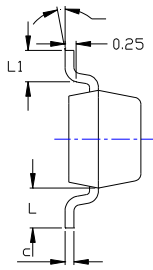
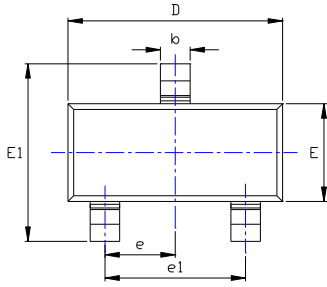


**Unclamped Inductive Switching (UIS) Test Circuit & Waveforms**

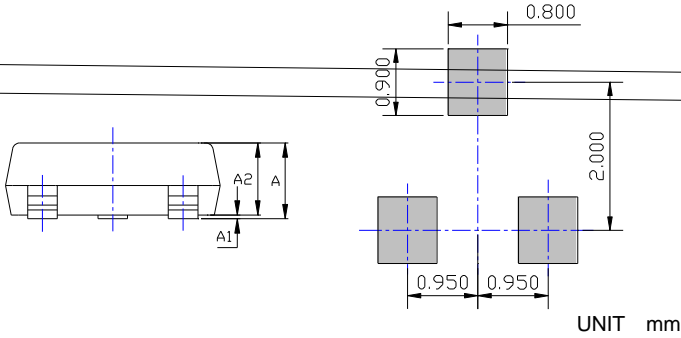


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## SOT-23 Package information



SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037TYP		0.950TYP	
e1	0.071	0.079	1.800	2.000
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